

#### **General Description**

The AOZ1010 is a high efficiency, simple to use, 2A buck regulator. The AOZ1010 works from a 4.5V to 16V input voltage range, and provides up to 2A of continuous output current with an output voltage adjustable down to 0.8V.

The AOZ1010 comes in an SO-8 package and is rated over a -40°C to +85°C ambient temperature range.

#### **Features**

- 4.5V to 16V operating input voltage range
- 130m $\Omega$  internal PFET switch for high efficiency: up to 95%
- Internal Schottky diode
- Internal soft start
- Output voltage adjustable to 0.8V
- 2A continuous output current
- Fixed 500kHz PWM operation
- Cycle-by-cycle current limit
- Short-circuit protection
- Thermal shutdown
- Small size SO-8 package

### **Applications**

- Point of load DC/DC conversion
- PCIe graphics cards
- Set top boxes
- DVD drives and HDD
- LCD panels
- Cable modems
- Telecom/networking/datacom equipment

# **Typical Application**

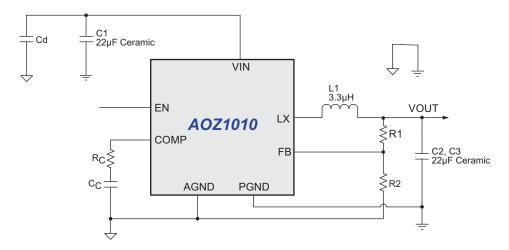


Figure 1. 3.3V/2A Buck Regulator



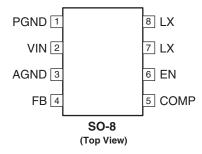
# **Ordering Information**

Part Number	Ambient Temperature Range	Package	Environmental		
AOZ1010AI	-40°C to +85°C	SO-8	RoHS		



All AOS Products are offering in packaging with Pb-free plating and compliant to RoHS standards. Please visit wwww.aosmd.com/web/rohs\_compliant.jsp for additional information.

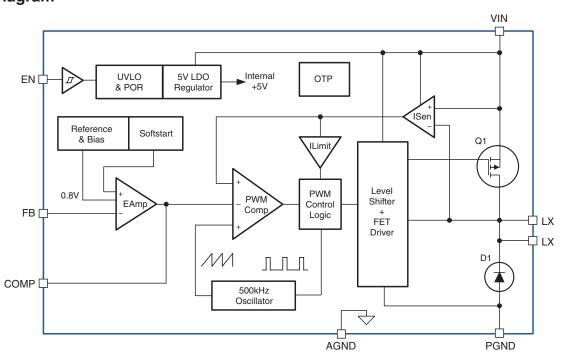
# **Pin Configuration**



# **Pin Description**

Pin Number	Pin Name Pin Function							
1	PGND	Power ground. Electrically needs to be connected to AGND.						
2 V <sub>IN</sub> Supply voltage input. When V <sub>IN</sub> rises above the UVLO threshold the device starts up.								
3	AGND Reference connection for controller section. Also used as thermal connection for controll section. Electrically needs to be connected to PGND.							
4	FB	The FB pin is used to determine the output voltage via a resistor divider between the output and GND.						
5	COMP	External loop compensation pin.						
6	EN	The enable pin is active high. Connect EN pin to $V_{\text{IN}}$ if not used. Do not leave the EN pin floating.						
7, 8	LX	PWM output connection to inductor. Thermal connection for output stage.						

# **Block Diagram**





### **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating			
Supply Voltage (V <sub>IN</sub> )	18V			
LX to AGND	-0.7V to V <sub>IN</sub> +0.3V			
EN to AGND	-0.3V to V <sub>IN</sub> +0.3V			
FB to AGND	-0.3V to 6V			
COMP to AGND	-0.3V to 6V			
PGND to AGND	-0.3V to +0.3V			
Junction Temperature (T <sub>J</sub> )	+150°C			
Storage Temperature (T <sub>S</sub> )	-65°C to +150°C			

### **Recommend Operating Ratings**

The device is not guaranteed to operate beyond the Maximum Operating Ratings.

Parameter	Rating
Supply Voltage (V <sub>IN</sub> )	4.5V to 16V
Output Voltage Range	0.8V to V <sub>IN</sub>
Ambient Temperature (T <sub>A</sub> )	-40°C to +85°C
Package Thermal Resistance SO-8 $(\Theta_{JA})^{(1)}$	87°C/W

#### Note:

1. The value of  $\Theta_{JA}$  is measured with the device mounted on 1-in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25\,^{\circ}\text{C}$ . The value in any given application depends on the user's specific board design.

#### **Electrical Characteristics**

 $T_A = 25$ °C,  $V_{IN} = V_{EN} = 12$ V,  $V_{OUT} = 3.3$ V unless otherwise specified<sup>(2)</sup>

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>IN</sub>	Supply Voltage		4.5		16	V
V <sub>UVLO</sub>	Input Under-Voltage Lockout Threshold	V <sub>IN</sub> Rising V <sub>IN</sub> Falling		4.00 3.70		V
I <sub>IN</sub>	Supply Current (Quiescent)	$I_{OUT} = 0$ , VFB = 1.2V, $V_{EN} > 1.2V$		2	3	mA
I <sub>OFF</sub>	Shutdown Supply Current	V <sub>EN</sub> = 0V		3	20	μA
$V_{FB}$	Feedback Voltage		0.782	0.8	0.818	V
	Load Regulation			0.5		%
	Line Regulation			1		%
I <sub>FB</sub>	Feedback Voltage Input Current				200	nA
V <sub>EN</sub>	EN Input Threshold	Off Threshold On Threshold	2.0		0.6	V
V <sub>HYS</sub>	EN Input Hysteresis			100		mV
MODULATO	OR				•	
f <sub>O</sub>	Frequency		350	500	600	kHz
D <sub>MAX</sub>	Maximum Duty Cycle		100			%
D <sub>MIN</sub>	Minimum Duty Cycle				6	%
	Error Amplifier Voltage Gain			500		V/V
	Error Amplifier Transconductance			200		μA/V
PROTECTION	ON		•			
I <sub>LIM</sub>	Current Limit		2.5		3.6	Α
	Over-Temperature Shutdown Limit	T <sub>J</sub> Rising T <sub>J</sub> Falling		145 100		°C
t <sub>SS</sub>	Soft Start Interval			4		ms
OUTPUT S	TAGE					
	High-Side Switch On-Resistance	V <sub>IN</sub> = 12V V <sub>IN</sub> = 5V		97 166	130 200	mΩ

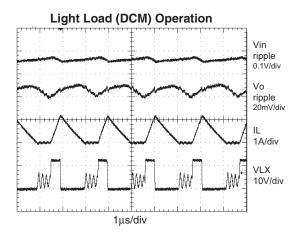
#### Note:

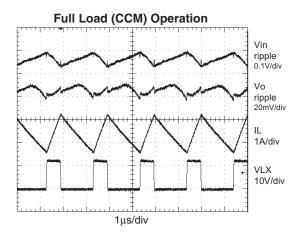
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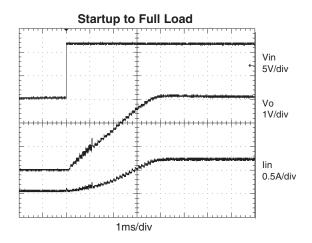
<sup>2.</sup> Specification in BOLD indicate an ambient temperature range of -40°C to +85°C. These specifications are guaranteed by design.

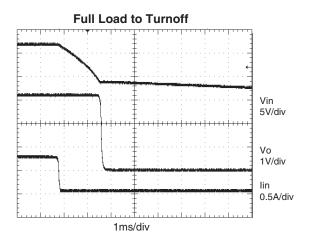


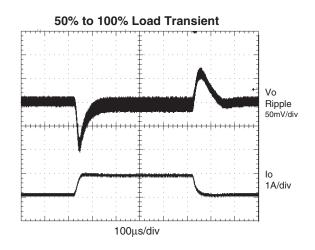
 $\begin{tabular}{ll} \textbf{Typical Performance Characteristics}\\ \textbf{Circuit of Figure 1. T}_{A} = 25^{\circ}\text{C}, \ V_{IN} = V_{EN} = 12\text{V}, \ V_{OUT} = 3.3\text{V} \ unless otherwise specified.} \end{tabular}$ 

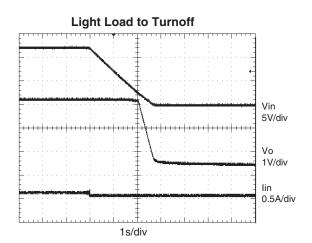






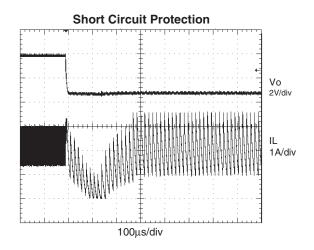


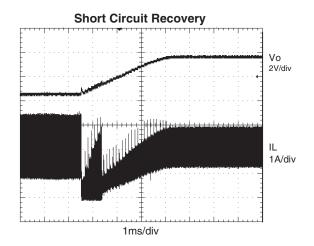


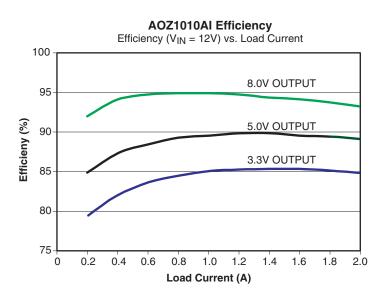




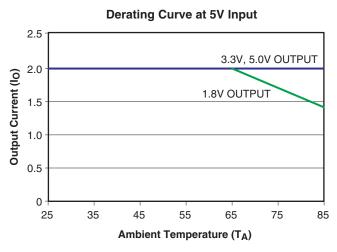
Typical Performance Characteristics (Continued) Circuit of Figure 1.  $T_A = 25$ °C,  $V_{IN} = V_{EN} = 12$ V,  $V_{OUT} = 3.3$ V unless otherwise specified.

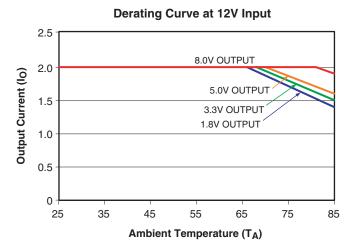






Thermal de-rating curves for SO-8 package part under typical input and output condition based on the evaluation board. 25°C ambient temperature and natural convection (air speed < 50LFM) unless otherwise specified.







#### **Detailed Description**

The AOZ1010 is a current-mode step down regulator with integrated high side PMOS switch and a low side freewheeling Schottky diode. It operates from a 4.5V to 16V input voltage range and supplies up to 2A of load current. The duty cycle can be adjusted from 6% to 100% allowing a wide range of output voltage. Features include enable control, Power-On Reset, input under voltage lockout, fixed internal soft-start and thermal shut down.

The AOZ1010 is available in SO-8 package.

#### **Enable and Soft Start**

The AOZ1010 has internal soft start feature to limit in-rush current and ensure the output voltage ramps up smoothly to regulation voltage. A soft start process begins when the input voltage rises to 4.0V and voltage on EN pin is HIGH. In soft start process, the output voltage is ramped to regulation voltage in typically 4ms. The 4ms soft start time is set internally.

The EN pin of the AOZ1010 is active high. Connect the EN pin to  $V_{\rm IN}$  if enable function is not used. Pulling EN to ground will disable the AOZ1010. Do not leave it open. The voltage on EN pin must be above 2.0V to enable the AOZ1010. When voltage on EN pin falls below 0.6V, the AOZ1010 is disabled. If an application circuit requires the AOZ1010 to be disabled, an open drain or open collector circuit should be used to interface to EN pin.

#### Steady-State Operation

Under steady-state conditions, the converter operates in fixed frequency and Continuous-Conduction Mode (CCM).

The AOZ1010 integrates an internal P-MOSFET as the high-side switch. Inductor current is sensed by amplifying the voltage drop across the drain to source of the high side power MOSFET. Output voltage is divided down by the external voltage divider at the FB pin. The difference of the FB pin voltage and reference is amplified by the internal transconductance error amplifier. The error voltage, which shows on the COMP pin, is compared against the current signal, which is sum of inductor current signal and ramp compensation signal, at PWM comparator input. If the current signal is less than the error voltage, the internal high-side switch is on. The inductor current flows from the input through the inductor to the output. When the current signal exceeds the error voltage, the high-side switch is off. The inductor current is freewheeling through the internal Schottky diode to output.

The AOZ1010 uses a P-Channel MOSFET as the high side switch. It saves the bootstrap capacitor normally seen in a circuit which is using an NMOS switch. It allows 100% turn-on of the upper switch to achieve linear regulation mode of operation. The minimum voltage drop from  $V_{IN}$  to  $V_{O}$  is the load current times DC resistance of MOSFET plus DC resistance of buck inductor. It can be calculated by equation below:

$$V_{O\ MAX} = V_{IN} - I_{O} \times (R_{DS(ON)} + R_{inductor})$$

where:

V<sub>O MAX</sub> is the maximum output voltage,

V<sub>IN</sub> is the input voltage from 4.5V to 16V,

I<sub>O</sub> is the output current from 0A to 2A,

 $R_{DS(ON)}$  is the on resistance of internal MOSFET, the value is between  $97m\Omega$  and  $200m\Omega$  depending on input voltage and junction temperature, and

R<sub>inductor</sub> is the inductor DC resistance.

#### Switching Frequency

The AOZ1010 switching frequency is fixed and set by an internal oscillator. The actual switching frequency could range from 350kHz to 600kHz due to device variation.

## **Output Voltage Programming**

Output voltage can be set by feeding back the output to the FB pin with a resistor divider network. In the application circuit shown in Figure 1. The resistor divider network includes  $R_2$  and  $R_3$ . Usually, a design is started by picking a fixed  $R_3$  value and calculating the required  $R_2$  with equation below:

$$V_O = 0.8 \times \left(1 + \frac{R_1}{R_2}\right)$$

Some standard values of R<sub>1</sub> and R<sub>2</sub> for the most commonly used output voltage values are listed in Table 1.

Table 1.

V <sub>O</sub> (V)	R <sub>1</sub> (kΩ)	R <sub>2</sub> (kΩ)			
0.8	1.0	Open			
1.2	4.99	10			
1.5	10	11.5			
1.8	12.7	10.2			
2.5	21.5	10			
3.3	31.6	10			
5.0	52.3	10			



The combination of  $R_1$  and  $R_2$  should be large enough to avoid drawing excessive current from the output, which will cause power loss.

Since the switch duty cycle can be as high as 100%, the maximum output voltage can be set as high as the input voltage minus the voltage drop on upper PMOS and inductor.

#### **Protection Features**

The AOZ1010 has multiple protection features to prevent system circuit damage under abnormal conditions.

## **Over Current Protection (OCP)**

The sensed inductor current signal is also used for over current protection. Since the AOZ1010 employs peak current mode control, the COMP pin voltage is proportional to the peak inductor current. The COMP pin voltage is limited to be between 0.4V and 2.5V internally. The peak inductor current is automatically limited cycle by cycle.

The cycle by cycle current limit threshold is set between 2.5A and 3.6A. When the load current reaches the current limit threshold, the cycle by cycle current limit circuit turns off the high side switch immediately to terminate the current duty cycle. The inductor current stops rising. The cycle by cycle current limit protection directly limits inductor peak current. The average inductor current is also limited due to the limitation on peak inductor current. When the cycle by cycle current limit circuit is triggered, the output voltage drops as the duty cycle is decreasing.

The AOZ1010 has internal short circuit protection to protect itself from catastrophic failure under output short circuit conditions. The FB pin voltage is proportional to the output voltage. Whenever FB pin voltage is below 0.2V, the short circuit protection circuit is triggered. As a result, the converter is shut down and hiccups at a frequency equal to 1/8 of normal switching frequency. The converter will start up via a soft start once the short circuit condition disappears. In short circuit protection mode, the inductor average current is greatly reduced because of the low hiccup frequency.

#### Power-On Reset (POR)

A power-on reset circuit monitors the input voltage. When the input voltage exceeds 4V, the converter starts operation. When input voltage falls below 3.7V, the converter will stop switching.

#### **Thermal Protection**

An internal temperature sensor monitors the junction temperature. It shuts down the internal control circuit and high side PMOS if the junction temperature exceeds 145°C. The regulator will restart automatically under the control of soft-start circuit when the junction temperature decreases to 100°C.

#### **Application Information**

The basic AOZ1010 application circuit is shown in Figure 1. Component selection is explained below.

#### **Input Capacitor**

The input capacitor ( $C_1$  in Figure 1), must be connected to the  $V_{IN}$  pin and PGND pin of the AOZ1010 to maintain steady input voltage and filter out the pulsing input current. A small decoupling capacitor ( $C_d$  in Figure 1), usually 1 $\mu$ F, should be connected to the  $V_{IN}$  pin and AGND pin for stable operation of the AOZ1010. The voltage rating of input capacitor must be greater than maximum input voltage plus ripple voltage.

The input ripple voltage can be approximated by the equation below:

$$\Delta V_{IN} = \frac{I_O}{f \times C_{IN}} \times \left(1 - \frac{V_O}{V_{IN}}\right) \times \frac{V_O}{V_{IN}}$$

Since the input current is discontinuous in a buck converter, the current stress on the input capacitor is another concern when selecting the capacitor. For a buck circuit, the RMS value of input capacitor current can be calculated by:

$$I_{CIN\_RMS} = I_O \times \sqrt{\frac{V_O}{V_{IN}} \left(1 - \frac{V_O}{V_{IN}}\right)}$$

If let m equal the conversion ratio:

$$\frac{V_O}{V_{IN}} = m$$

The relationship between the input capacitor RMS current and voltage conversion ratio is calculated and shown in Figure 2 on the next page. It can be seen that when  $V_O$  is half of  $V_{IN},\,C_{IN}$  is under the worst current stress. The worst current stress on  $C_{IN}$  is 0.5 x  $I_O$ .

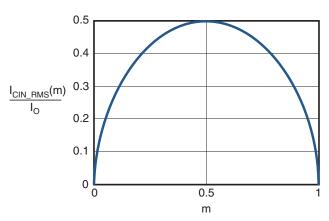


Figure 2. I<sub>CIN</sub> vs. Voltage Conversion Ratio

For reliable operation and best performance, the input capacitors must have current rating higher than I<sub>CIN\_RMS</sub> at the worst operating conditions. Ceramic capacitors are preferred for input capacitors because of their low ESR and high ripple current rating. Depending on the application circuits, other low ESR tantalum capacitors or aluminum electrolytic capacitors may also be used. When selecting ceramic capacitors, X5R or X7R type dielectric ceramic capacitors are preferred for their better temperature and voltage characteristics. Note that the ripple current rating from capacitor manufacturers is based on certain amount of life time. Further de-rating may be necessary for practical design requirement.

#### Inductor

The inductor is used to supply constant current to the output when it is driven by a switching voltage. For a given input and output voltage, inductance and switching

frequency together decide the inductor ripple current, which is:

$$\Delta I_L = \frac{V_O}{f \times L} \times \left(1 - \frac{V_O}{V_{IN}}\right)$$

The peak inductor current is:

$$I_{Lpeak} = I_O + \frac{\Delta I_L}{2}$$

High inductance gives low inductor ripple current but requires a larger size inductor to avoid saturation. Low ripple current reduces inductor core losses. Low ripple current also reduces RMS current through the inductor and switches, which results in less conduction loss.

When selecting the inductor, make sure it is able to handle the peak current at the highest operating temperature without saturation.

The inductor takes the highest current in a buck circuit. The conduction loss on the inductor needs to be checked for thermal and efficiency requirements.

Surface mount inductors in different shape and styles are available from Coilcraft, Elytone and Murata. Shielded inductors are small and radiate less EMI noise, but they cost more than unshielded inductors. The choice depends on EMI requirement, price and size.

Table 2 lists some inductors for typical output voltage design.

**Table 2. Typical Inductors** 

V <sub>OUT</sub>	L1	Manufacture
5.0V	Unshielded, 4.7µH, LQH55DN4R7M03	MURATA
	Shielded, 4.7µH, LQH66SN4R7M03	MURATA
	Shielded, 5.8µH, ET553-5R8	ELYTONE
	Unshielded, 6.7µH, DO3316P-682MLD	Coilcraft
3.3V	Unshielded, 4.7µH, LQH55DN3R3M03	MURATA
	Shielded, 4.7µH, LQH66SN3R3M03	MURATA
	Shielded, 3.3µH, ET553-3R3	ELYTONE
	Unshielded, 4.7µH, DO3316P-472MLD	Coilcraft
	Unshielded, 4.7µH, DO1813P-472HC	Coilcraft
1.8V	Unshielded, 2.2µH, LQH55DN1R5M03	MURATA
	Shielded, 2.2µH, LQH66SN1R5M03	MURATA
	Shielded, 2.2µH, ET553-2R2	ELYTONE
	Unshielded, 2.2µH, DO3316P-222MLD	Coilcraft
	Unshielded, 2.2µH, DO1813P-222HC	Coilcraft



#### **Output Capacitor**

The output capacitor is selected based on the DC output voltage rating, output ripple voltage specification, and ripple current rating.

The selected output capacitor must have a higher rated voltage specification than the maximum desired output voltage including ripple. De-rating needs to be considered for long term reliability.

Output ripple voltage specification is another important factor for selecting the output capacitor. In a buck converter circuit, output ripple voltage is determined by inductor value, switching frequency, output capacitor value and ESR. It can be calculated by the equation below:

$$\Delta V_O = \Delta I_L \times \left( ESR_{CO} + \frac{1}{8 \times f \times C_O} \right)$$

where.

CO is output capacitor value, and

ESR<sub>CO</sub> is the equivalent series resistance of the output capacitor.

When low ESR ceramic capacitor is used as output capacitor, the impedance of the capacitor at the switching frequency dominates. Output ripple is mainly caused by capacitor value and inductor ripple current. The output ripple voltage calculation can be simplified to:

$$\Delta V_O = \Delta I_L \times \frac{1}{8 \times f \times C_O}$$

If the impedance of ESR at switching frequency dominates, the output ripple voltage is mainly decided by capacitor ESR and inductor ripple current. The output ripple voltage calculation can be further simplified to:

$$\Delta V_O = \Delta I_I \times ESR_{CO}$$

For lower output ripple voltage across the entire operating temperature range, X5R or X7R dielectric type of ceramic, or other low ESR tantalum capacitor or aluminum electrolytic capacitor may also be used as output capacitors.

In a buck converter, output capacitor current is continuous. The RMS current of output capacitor is decided by the peak to peak inductor ripple current. It can be calculated by:

$$I_{CO\_RMS} = \frac{\Delta I_L}{\sqrt{12}}$$

Usually, the ripple current rating of the output capacitor is a smaller issue because of the low current stress. When the buck inductor is selected to be very small and inductor ripple current is high, output capacitor could be overstressed.

#### **Loop Compensation**

The AOZ1010 employs peak current mode control for easy use and fast transient response. Peak current mode control eliminates the double pole effect of the output L&C filter. It greatly simplifies the compensation loop design.

With peak current mode control, the buck power stage can be simplified to be a one-pole and one-zero system in frequency domain. The pole is dominant pole and can be calculated by:

$$f_{P1} = \frac{1}{2\pi \times C_O \times R_L}$$

The zero is a ESR zero due to output capacitor and its ESR. It is can be calculated by:

$$f_{Z1} = \frac{1}{2\pi \times C_O \times ESR_{CO}}$$

where;

CO is the output filter capacitor,

R<sub>L</sub> is load resistor value, and

ESR<sub>CO</sub> is the equivalent series resistance of output capacitor.

The compensation design is actually to shape the converter close loop transfer function to get desired gain and phase. Several different types of compensation networks can be used for AOZ1010. For most cases, a series capacitor and resistor network connected to the COMP pin sets the pole-zero and is adequate for a stable high-bandwidth control loop.

In the AOZ1010, FB pin and COMP pin are the inverting input and the output of internal transconductance error amplifier. A series R and C compensation network connected to COMP provides one pole and one zero. The pole is:

$$f_{P2} = \frac{G_{EA}}{2\pi \times C_C \times G_{VEA}}$$

where;

 $G_{EA}$  is the error amplifier transconductance, which is 200 x 10<sup>-6</sup> A/V.

 $G_{\mbox{\scriptsize VEA}}$  is the error amplifier voltage gain, which is 500 V/V, and  $C_{\mbox{\scriptsize C}}$  is compensation capacitor.



The zero given by the external compensation network, capacitor  $C_C$  ( $C_5$  in Figure 1), and resistor  $R_C$  ( $R_1$  in Figure 1), is located at:

$$f_{Z2} = \frac{1}{2\pi \times C_C \times R_C}$$

To design the compensation circuit, a target crossover frequency  $f_{\text{C}}$  for close loop must be selected. The system crossover frequency is where control loop has unity gain. The crossover frequency is also called the converter bandwidth. Generally a higher bandwidth means faster response to load transient. However, the bandwidth should not be too high because of system stability concerns. When designing the compensation loop, converter stability under all line and load condition must be considered.

Usually, it is recommended to set the bandwidth to be less than 1/10 of switching frequency. The AOZ1010 operates at a fixed switching frequency range from 350kHz to 600kHz. The recommended crossover frequency is less than 30kHz.

$$f_C = 30kHz$$

The strategy for choosing  $R_C$  and  $C_C$  is to set the cross over frequency with  $R_C$  and set the compensator zero with  $C_C$ . Using selected crossover frequency,  $f_C$ , to calculate  $R_C$ :

$$R_C = f_C \times \frac{V_O}{V_{FR}} \times \frac{2\pi \times C_O}{G_{FA} \times G_{CS}}$$

where.

f<sub>C</sub> is the desired crossover frequency,

 $V_{FB}$  is 0.8V,

 $G_{EA}$  is the error amplifier transconductance, which is 200 x 10<sup>-6</sup> A/V, and

 $G_{CS}$  is the current sense circuit transconductance, which is 5.64 A/V.

The compensation capacitor  $C_C$  and resistor  $R_C$  together make a zero. This zero is put somewhere close to the dominate pole,  $f_{P1}$ , but lower than 1/5 of the selected crossover frequency.  $C_C$  can is selected by:

$$C_C = \frac{1.5}{2\pi \times R_C \times f_{P1}}$$

The previous equation can also be simplified to:

$$C_C = \frac{C_O \times R_L}{R_C}$$

An easy-to-use application software which helps to design and simulate the compensation loop can be found at www.aosmd.com.

Table 3 lists the values for a typical output voltage design when output is  $44\mu F$  ceramics capacitor.

Table 3.

V <sub>OUT</sub>	L1 R <sub>C</sub>		cc
1.8V	2.2µH	20kΩ	1.5nF
3.3V	3.3µH	31.6kΩ	1.0nF
5V	4.7µH	49.9kΩ	1.0nF
8V	8V 10μH		0.82nF

# Thermal Management and Layout Consideration

In the AOZ1010 buck regulator circuit, high pulsing current flows through two circuit loops. The first loop starts from the input capacitors, to the  $V_{IN}$  pin, to the LX pins, to the filter inductor, to the output capacitor and load, and then returns to the input capacitor through ground. Current flows in the first loop when the high side switch is on. The second loop starts from the inductor, to the output capacitors and load, to the PGND pin of the AOZ1010, and to the LX pins of the AZO1010. Current flows in the second loop when the low side diode is on.

In PCB layout, minimizing the two loops area reduces the noise of this circuit and improves efficiency. A ground plane is recommended to connect input capacitor, output capacitor, and PGND pin of the AOZ1010.

In the AOZ1010 buck regulator circuit, the two major power dissipating components are the AOZ1010 and output inductor. The total power dissipation of converter circuit can be measured by input power minus output power.

$$P_{total\_loss} = V_{IN} \times I_{IN} - V_O \times I_O$$

The power dissipation of inductor can be approximately calculated by output current and DCR of inductor.

$$P_{inductor\ loss} = I_O^2 \times R_{inductor} \times 1.1$$



The junction to ambient temperature can be got from power dissipation in the AOZ1010 and thermal impedance from junction to ambient.

$$T_{(jun-amb)} = (P_{totalloss} - P_{inductorloss}) \times \Theta_{JA}$$

The maximum junction temperature of AOZ1010 is 145°C, which limits the maximum load current capability. Please see the thermal de-rating curves for the maximum load current of the AOZ1010 under different ambient temperatures.

The thermal performance of the AOZ1010 is strongly affected by the PCB layout. Extra care should be taken by users during the design process to ensure that the IC will operate under the recommended environmental conditions.

Several layout tips are listed below for the best electric and thermal performance. Figure 3 below illustrates a single layer PCB layout example as a reference.

1. Do not use thermal relief connection to the  $V_{IN}$  and the PGND pin. Pour a maximized copper area to the PGND pin and the  $V_{IN}$  pin to help thermal dissipation.

- Input capacitor should be connected to the V<sub>IN</sub> pin and the PGND pin as close as possible.
- A ground plane is preferred. If a ground plane is not used, separate PGND from AGND and connect them only at one point to avoid the PGND pin noise coupling to the AGND pin. In this case, a decoupling capacitor should be connected between V<sub>IN</sub> pin and AGND pin.
- 4. Make the current trace from LX pins to L to Co to the PGND as short as possible.
- 5. Pour copper plane on all unused board area and connect it to stable DC nodes, like  $V_{IN}$ , GND, or  $V_{OUT}$ .
- 6. The two LX pins are connected to the internal PFET drain. They are low resistance thermal conduction path and most noisy switching node. Connect a copper plane to the LX pin to help thermal dissipation. This copper plane should not be too large otherwise switching noise may be coupled to other parts of the circuit.
- 7. Keep sensitive signal traces such as trace connecting FB pin and COMP pin away from the LX pins.

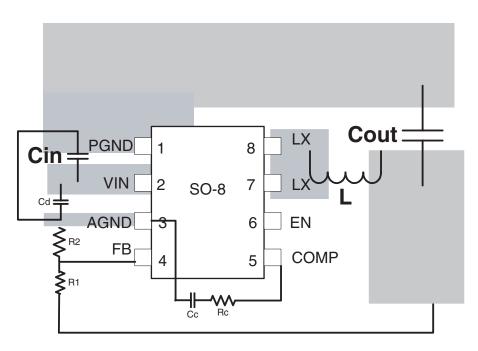
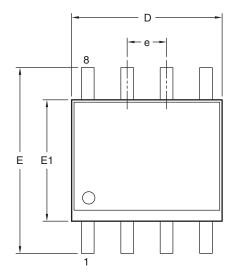


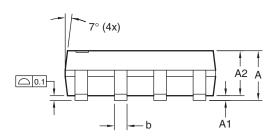
Figure 3. AOZ1010 PCB Layout

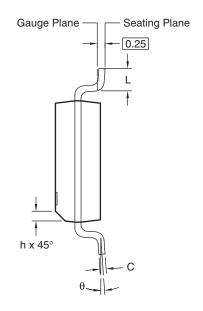
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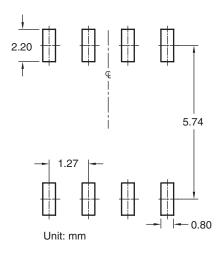


# Package Dimensions, SO-8L









# **Dimensions in millimeters**

Symbols	Min.	Nom.	Max.
Α	1.35	1.65	1.75
A1	0.10	_	0.25
A2	1.25	1.50	1.65
b	0.31	_	0.51
С	0.17	_	0.25
D	4.80	4.90	5.00
E1	3.80	3.90	4.00
е	1	1.27 BSC	
E	5.80	6.00	6.20
h	0.25	_	0.50
L	0.40	_	1.27
θ	0°	_	8°

#### **Dimensions in inches**

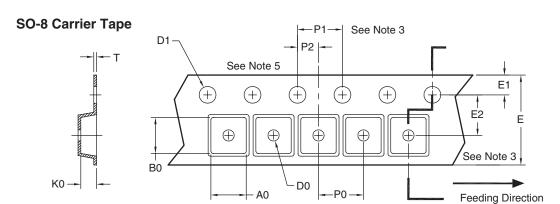
Symbols	Min.	Nom.	Max.
Α	0.053	0.065	0.069
A1	0.004	_	0.010
A2	0.049	0.059	0.065
b	0.012	_	0.020
С	0.007	_	0.010
D	0.189	0.193	0.197
E1	0.150	0.154	0.157
е	0	.050 BS	С
Е	0.228	0.236	0.244
h	0.010	_	0.020
L	0.016		0.050
θ	0°	_	8°

#### Notes:

- 1. All dimensions are in millimeters.
- 2. Dimensions are inclusive of plating
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

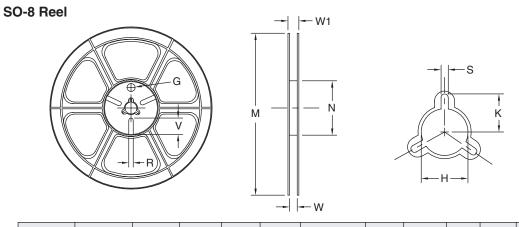


# **Tape and Reel Dimensions**



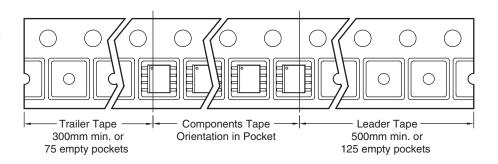
Unit: mm

Package	A0	В0	K0	D0	D1	Е	E1	E2	P0	P1	P2	Т
SO-8	6.40	5.20	2.10	1.60	1.50	12.00	1.75	5.50	8.00	4.00	2.00	0.25
(12mm)	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10



Tape Size	Reel Size	M	N	W	W1	Н	K	S	G	R	V
12mm	ø330	ø330.00	ø97.00	13.00	17.40	ø13.00	10.60	2.00	_	_	_
		±0.50	±0.10	±0.30	±1.00	+0.50/-0.20		±0.50			

**SO-8 Tape** Leader/Trailer & Orientation





# **AOZ1010 Package Marking**

